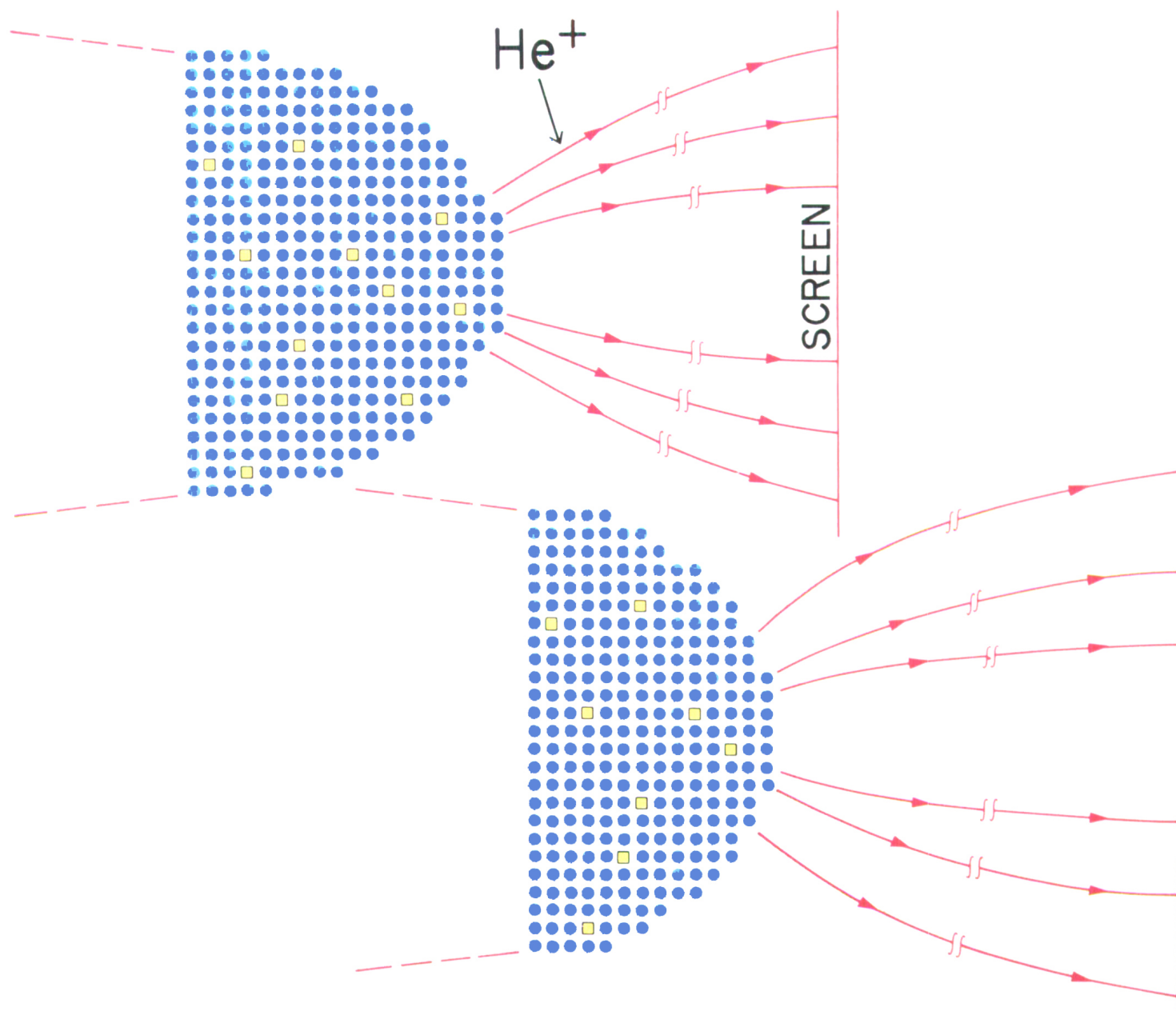
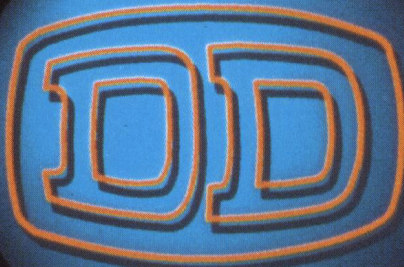


## In Pursuit of the Lattice Vacancy





# A NEW CLUSTER IS BORN



## **General Ionex acquired by High Voltage Engineering Europa B.V.**

In December 1987 High Voltage Engineering Europa B.V. (HVEE) acquired Dowlish Developments Ltd (DD), an accelerator tube manufacturer located in the United Kingdom.

On April 10, 1989, HVEE purchased the General Ionex Analytical Product Group from Genus Inc. based in the United States.

Through this acquisition HVEE positions itself as the largest and most diverse manufacturer of particle accelerators for the scientific and industrial research communities.

The acquired General Ionex (GI) product lines, which include the Tandetron accelerator systems and Model 4175 RBS Analyser, will be manufactured in HVEE's new, well-equipped facility in Amersfoort, The Netherlands.

World wide marketing of all products from HVEE, DD and GI will originate from HVEE Amersfoort with sales and service offices in the USA, Europe and Japan.

After addition of the newly acquired products HVEE's product lines include:

### *- Ion Accelerator Systems*

- Air insulated accelerators up to 500 kV
- Single ended Van de Graaff accelerators up to 4 MV
- Tandem Tandetron accelerators up to 3 MV/TV

### *- Research ion implanters*

- Beam energies 10 keV-9 MeV and higher

### *- Systems for ion beam analysis*

- Systems for RBS, PIXE, PIGE, NRA, ERD, MACS and MEIS

### *- Components*

- HV power supplies, electron and ion accelerator tubes, ion sources beamline components, beam monitoring equipment, UHV sample manipulators, etc.

For further information on this transaction and product literature please contact HVEE in Amersfoort/NL.

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# MRS BULLETIN

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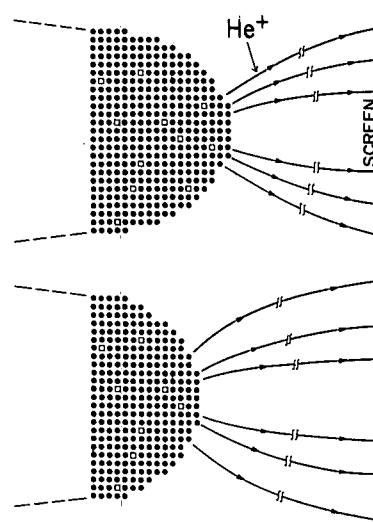
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**ON THE COVER:** Schematic shows how 1990 Von Hippel Award recipient Robert W. Balluffi and Dave Seidman, with the help of then graduate student Arnie Berger, used field ion microscopy to study lattice defects. For more information, see "In Pursuit of the Lattice Vacancy" on p. 23.



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### Design/Production

C. Love, W. Appman, J. Probert

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#### Advertising Offices

9800 McKnight Road  
Pittsburgh, PA 15237  
Telephone (412) 367-3036  
Fax (412) 367-4373

### Associate Editor—Europe

I. W. Boyd  
University College London  
Dept. of Electronic and  
Electrical Engineering  
Torrington Place  
London WC1 E7 JE  
United Kingdom  
71-387-7050  
ext. 3956 or 7304

### MRS Office of Public Affairs

2000 Florida Ave. NW, Third Floor  
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The Society's interdisciplinary approach to the exchange of technical information is qualitatively different from that provided by single-discipline professional societies because it promotes technical exchange across the various fields of science affecting materials development. MRS sponsors two major international annual meetings encompassing approximately 40 topical symposia, as well as numerous single-topic scientific meetings each year. It recognizes professional and technical excellence, conducts short courses, and fosters technical exchange in various local geographic regions through Section activities and University Chapters.

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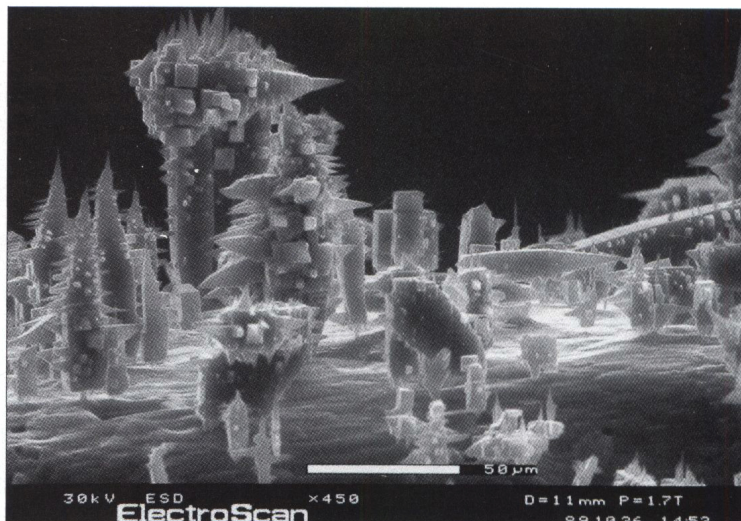
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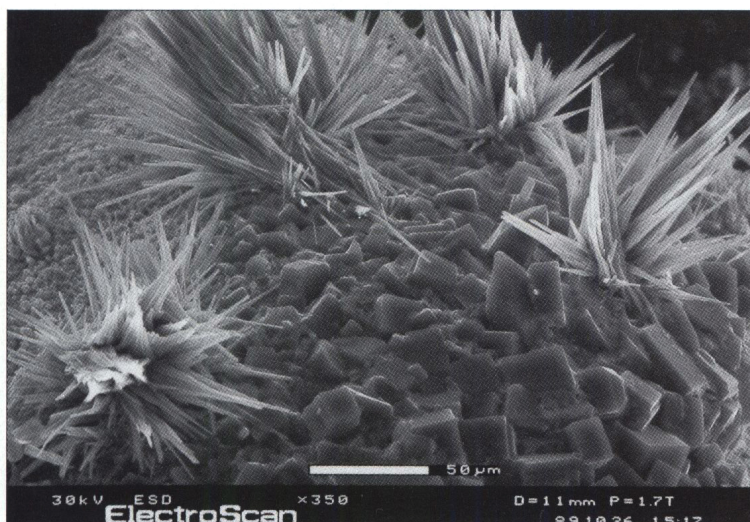
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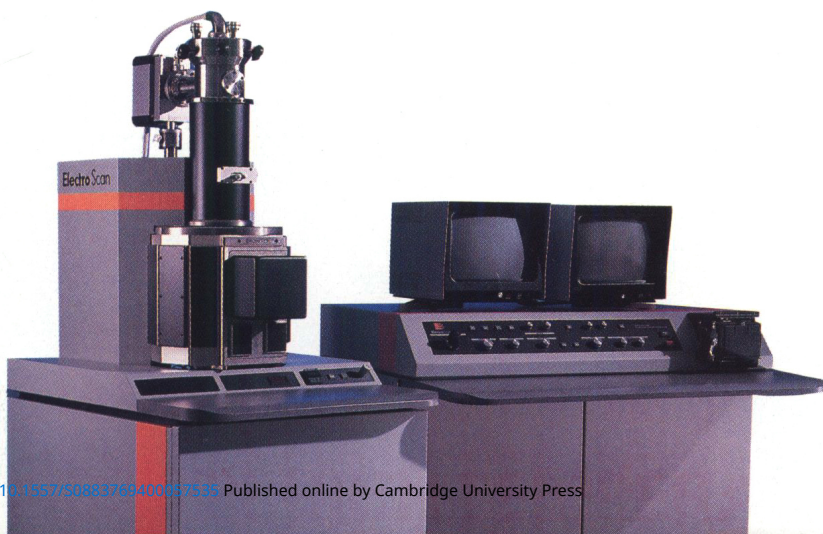
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